



NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK

HMC694LP4 / 694LP4E

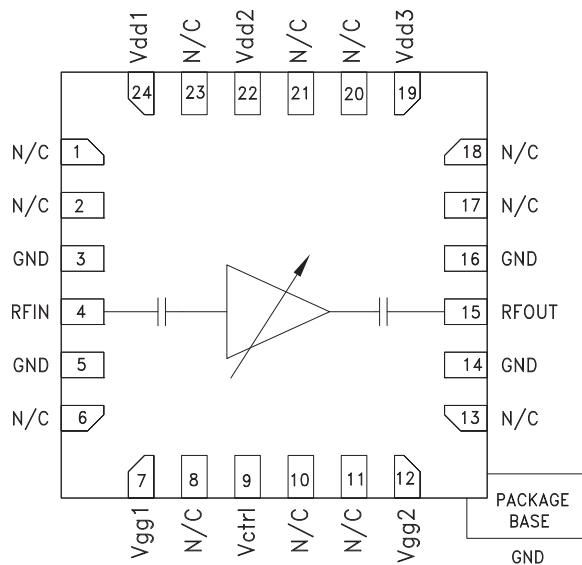
GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

Typical Applications

The HMC694LP4(E) is ideal for:

- Point-to-Point Radio
- Point-to-Multi-Point Radio
- EW & ECM
- X-Band Radar
- Test Equipment

Functional Diagram



Features

- Wide Gain Control Range: 23 dB
- Single Control Voltage
- Output IP3 @ Max Gain: +30 dBm
- Output P1dB: +22 dBm
- No External Matching
- 24 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC694LP4(E) is a GaAs MMIC PHEMT analog variable gain amplifier which operates between 6 and 17 GHz. Ideal for microwave radio applications, the amplifier provides up to 22 dB of gain, output P1 dB of up to +22 dBm, and up to +30 dBm of output IP3 at maximum gain, while requiring only 175 mA from a +5V supply. A gate bias pin (Vctrl) is provided to allow variable gain control up to 23 dB. Gain flatness is excellent making the HMC694LP4E ideal for EW, ECM and radar applications. The HMC694LP4E is housed in a RoHS compliant 4x4 mm QFN leadless package and is compatible with high volume surface mount manufacturing.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd1, 2, 3} = 5\text{V}$, $V_{ctrl} = -2\text{V}$, $I_{dd} = 170\text{mA}^*$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		6 - 10		10 - 17			GHz
Gain	19	22		14	18		dB
Gain Flatness		± 1			± 1.5		dB
Gain Variation Over Temperature		0.015			0.015		dB/ °C
Gain Control Range		23			20		dB
Noise Figure		6	7.5		6	6.5	dB
Input Return Loss		15			8		dB
Output Return Loss		10			8		dB
Output Power for 1 dB Compression (P1dB)	19	21		21	22		dBm
Saturated Output Power (Psat)		22			23		dBm
Output Third Order Intercept (IP3)		30			30		dBm
Total Supply Current (Idd)		175			175		mA

*Set Vctrl = -2V and then adjust Vgg1, 2 between -2V to 0V (typ. -0.8V) to achieve Idd = 170mA typical.

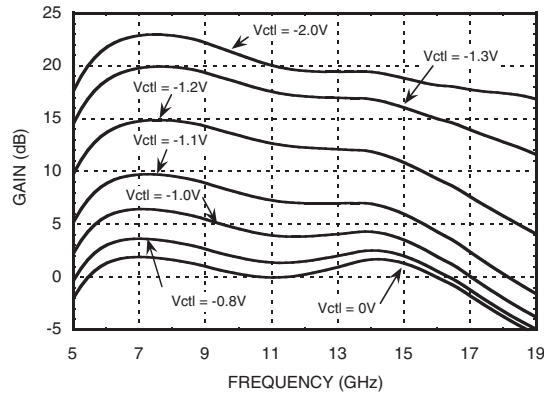
For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

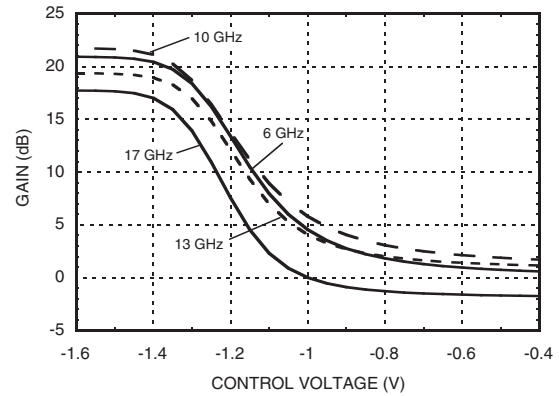
Application Support: Phone: 978-250-3343 or apps@hittite.com

GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

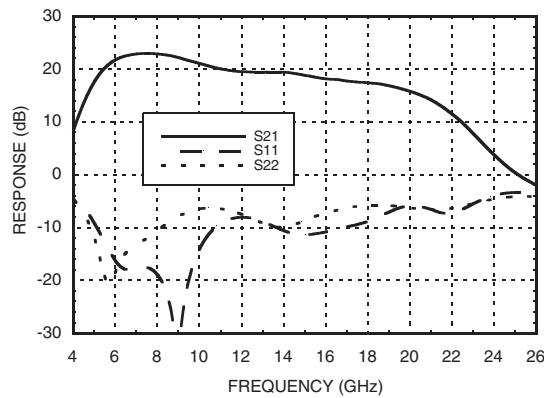
Control Voltage Range vs. Gain



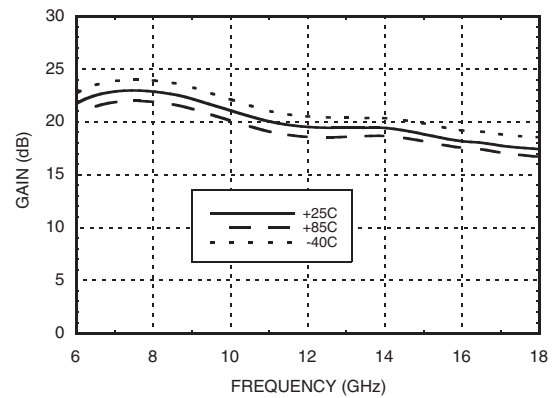
Gain vs. Control Voltage



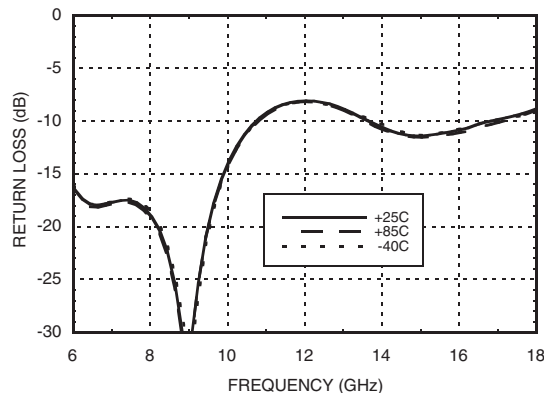
Broadband Gain & Return Loss



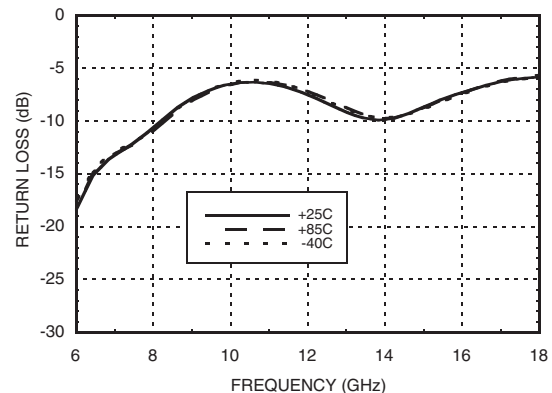
Gain vs. Temperature



Input Return Loss vs. Temperature

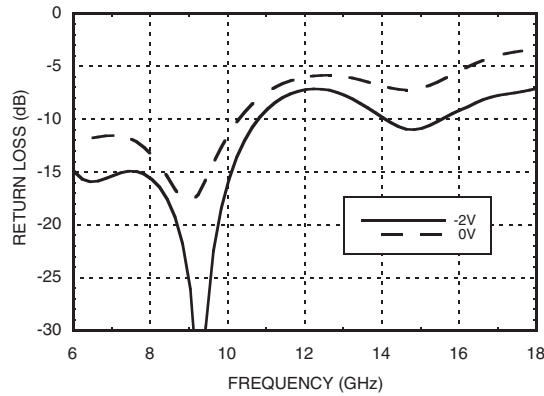


Output Return Loss vs. Temperature

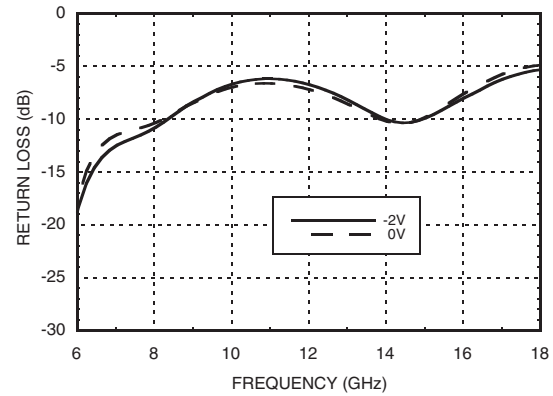


GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

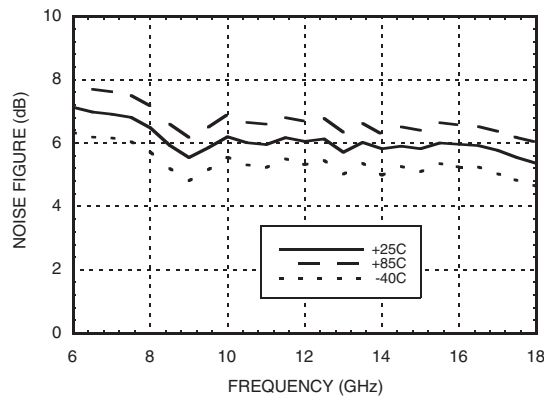
Return Loss @ Voltage Extreme



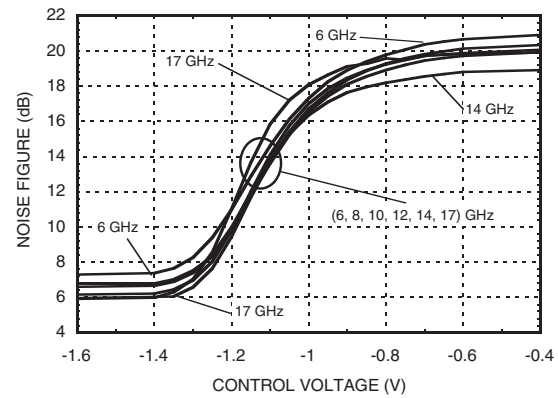
Output Return Loss @ Voltage Extreme



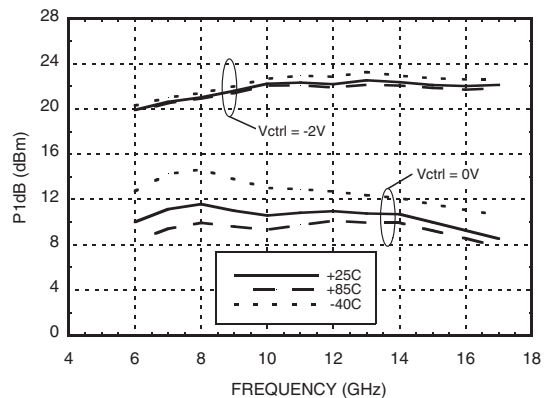
Noise Figure vs. Temperature



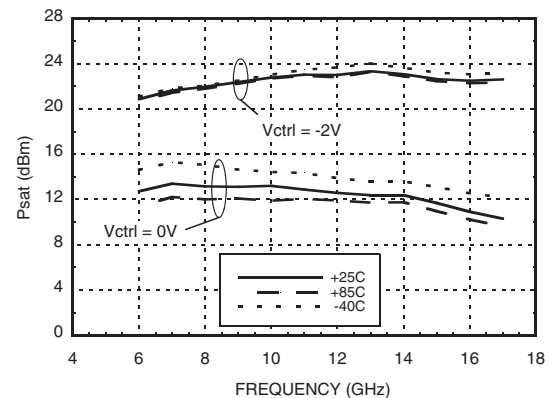
Noise Figure vs. CTRL



P1dB vs. Temperature



Psat vs. Temperature

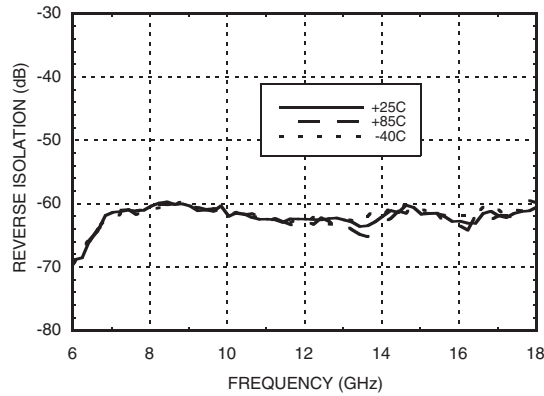


[1] Tested with broadband bias tee on RF ports and C1 = 10,000pF

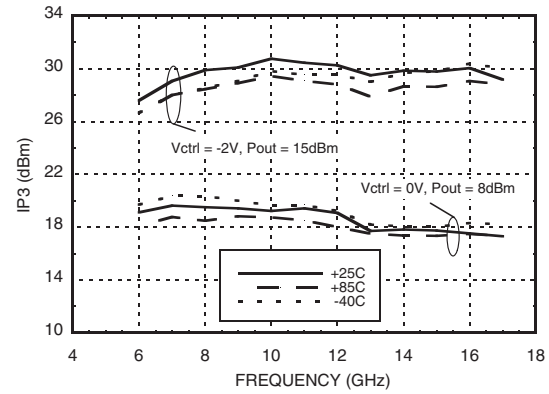
[2] C1, C6 and C8 = 100pF, L1 = 24nF

GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

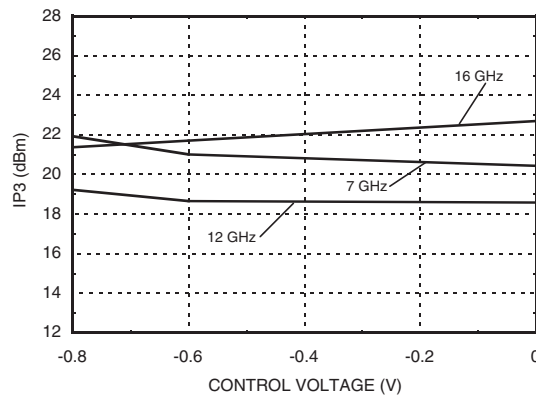
Reverse Isolation vs. Temperature



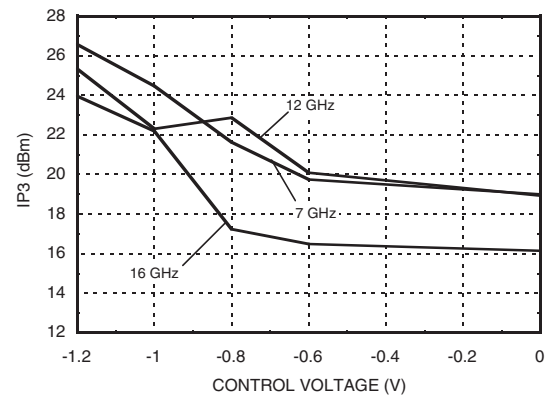
Output IP3 vs. Temperature



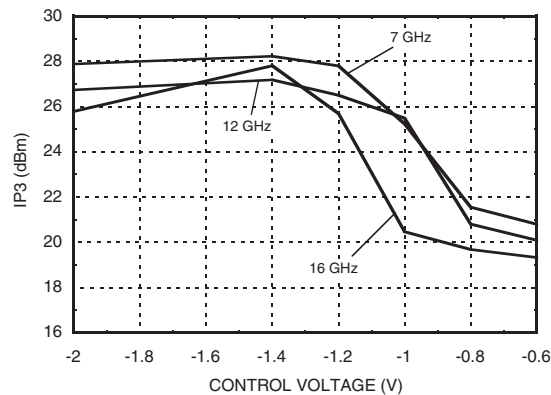
Output IP3 @ 0 dBm



Output IP3 @ 5 dBm



Output IP3 @ 10 dBm



GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3)	+5.5V
Gate Bias Voltage (Vgg1, 2)	-3 to 0V
Gain Control Voltage (Vctrl)	-3 to 0V
RF Power Input	+5 dBm
Channel Temperature	175 °C
Continuous P _{dis} (T = 85 °C) (derate 10.2 mW/°C above 85 °C) [1]	0.92 W
Thermal Resistance (Channel to ground paddle)	97.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

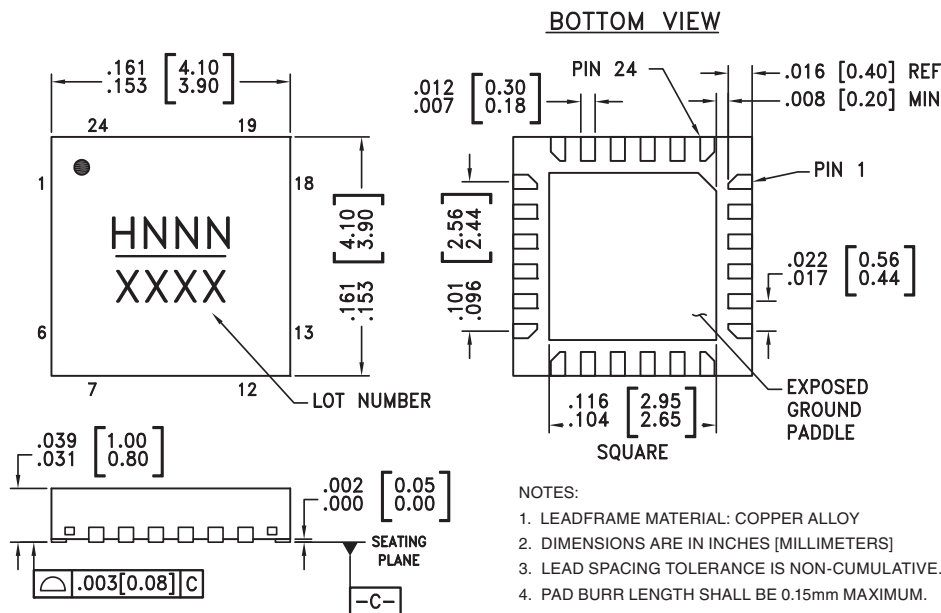
Bias Voltage

Vdd1,2,3 (V)	Idd Total (mA)
+5.0	170
Vgg1,2 (V)	Igg Total (mA)
0V to -2V	<3 μ A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC694LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H694 XXXX
HMC694LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H694</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com



MICROWAVE CORPORATION

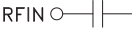
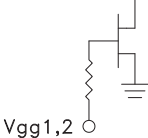
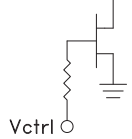
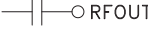
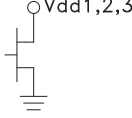
v02.1108



HMC694LP4 / 694LP4E

GaAs MMIC ANALOG VARIABLE GAIN AMPLIFIER, 6 - 17 GHz

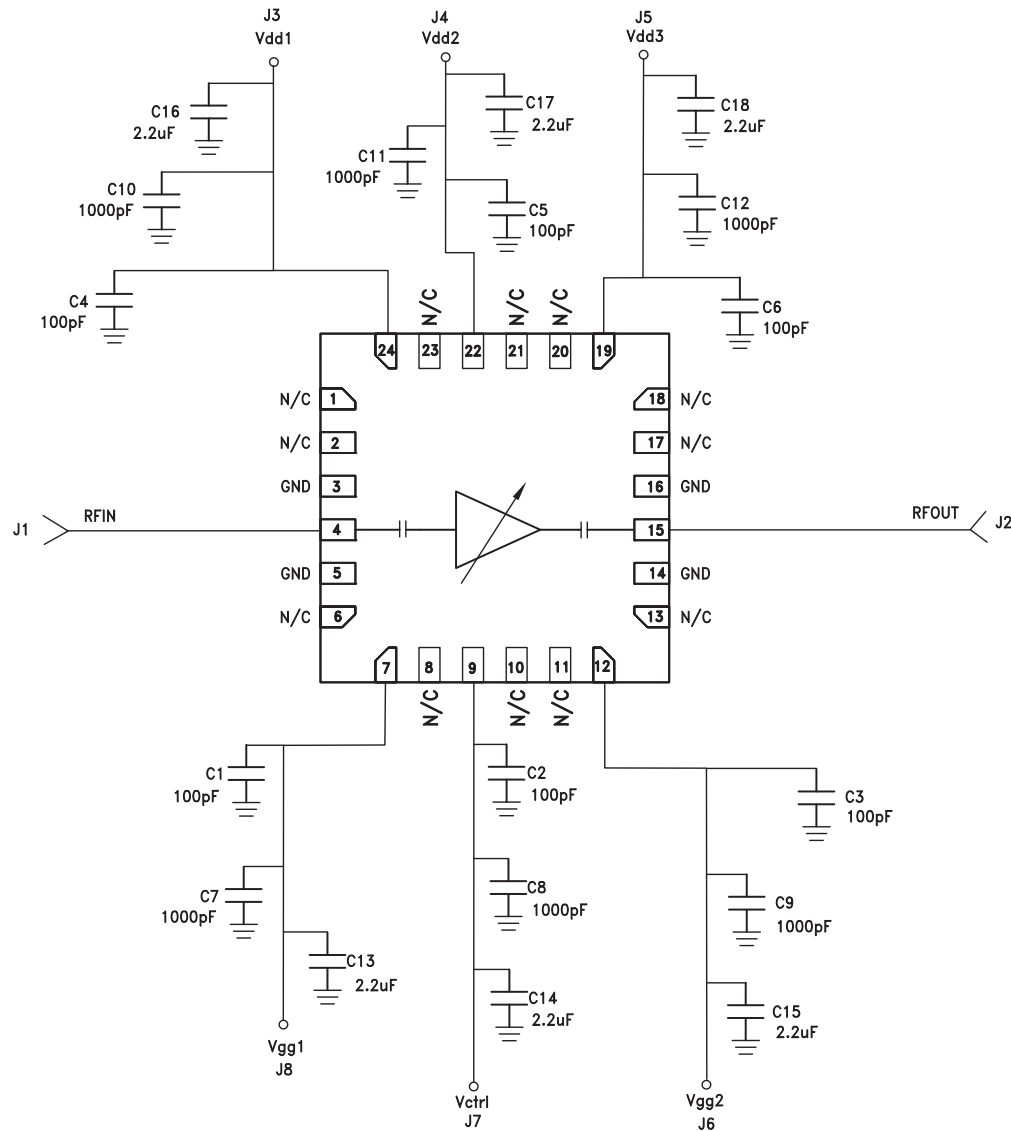
Pin Descriptions

Pad Number	Function	Description	Interface Schematic
1, 2, 6, 8, 10, 11, 13, 17, 18, 20, 21, 23	N/C	No Connection	
3, 5, 14, 16	GND	Die bottom must be connected to RF/DC ground.	
4	RFIN	This pad is AC coupled and matched to 50 Ohm.	
7, 12	Vgg1, 2	Gate control for amplifier. Adjust voltage to achieve typical Idd. Please follow "MMIC Amplifier Biasing Procedure" application note.	
9	Vctrl	Gain control Voltage for the amplifier. See assembly diagram for required external components.	
15	RFOUT	This pad is AC coupled and matched to 50 Ohm.	
19, 22, 24	Vdd1, 2, 3	Drain Bias Voltage for the amplifier. See assembly diagram for required external components	

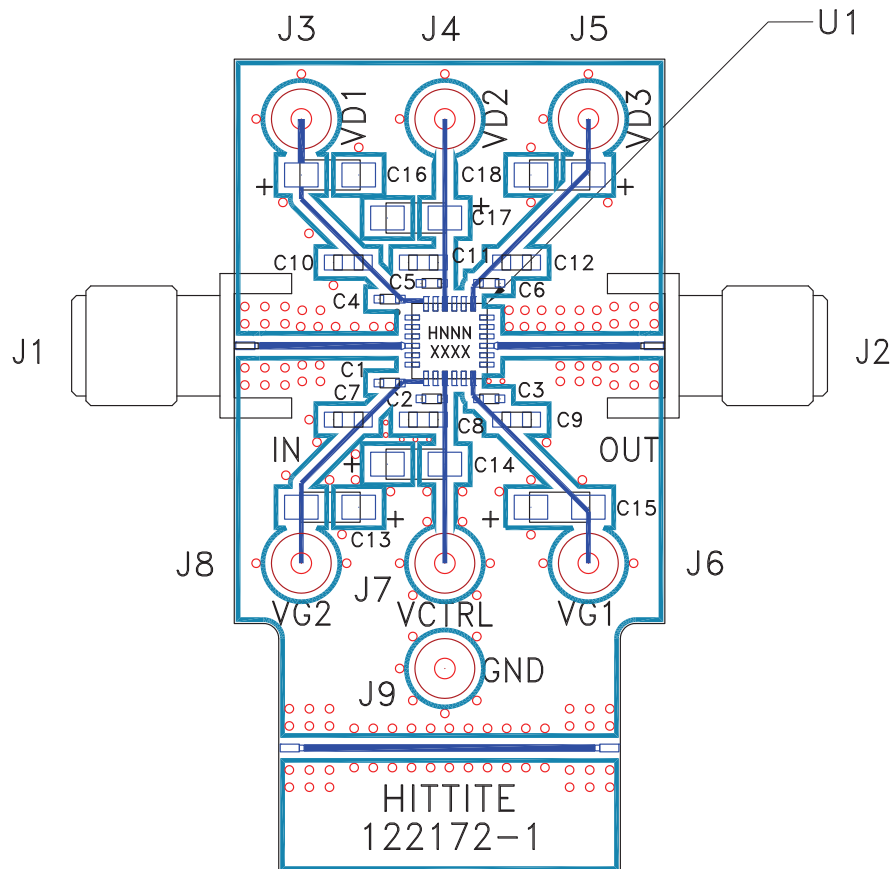
12

VARIABLE GAIN AMPLIFIERS - ANALOG - SMT

Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 122174 [1]

Item	Description
J1, J2	PCB Mount SMA RF Connectors
J3 - J9	DC Pin
C1 - C6	100 pF Capacitor, 0402 Pkg.
C7 - C12	1000 pF Capacitor, 0603 Pkg.
C13 - C18	2.2 μ F Capacitor, CASE A
U1	HMC694LP4(E) Variable Gain Amplifier
PCB [2]	122172 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9